

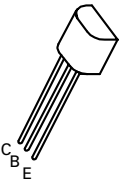
PNP SILICON PLANAR MEDIUM POWER
HIGH GAIN TRANSISTOR

ISSUE 1 - January 1997

ZTX1149A

FEATURES

- * $V_{CEO} = -25V$
- * 3 Amp Continuous Current
- * 10 Amp Pulse Current
- * Low Saturation Voltage
- * High Gain



E-Line
TO92 Compatible

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	ZTX1149A	UNIT
Collector-Base Voltage	V_{CBO}	-30	V
Collector-Emitter Voltage	V_{CEO}	-25	V
Emitter-Base Voltage	V_{EBO}	-5	V
Peak Pulse Current	I_{CM}	-10	A
Continuous Collector Current	I_C	-3	A
Base Current	I_B	-500	mA
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	1	W
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +200	$^{\circ}C$

ZTX1149A

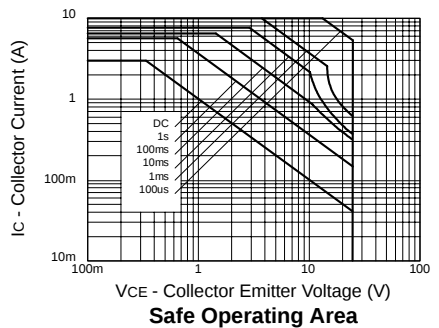
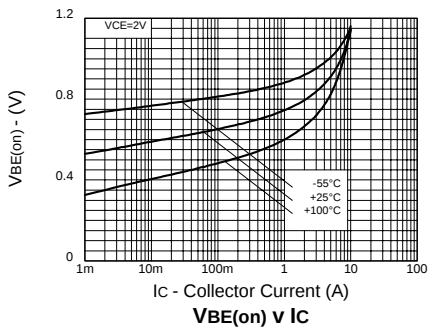
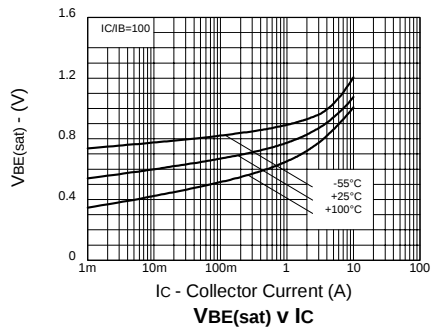
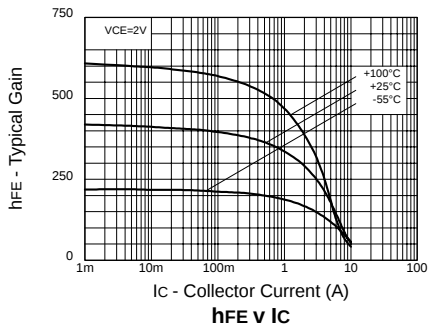
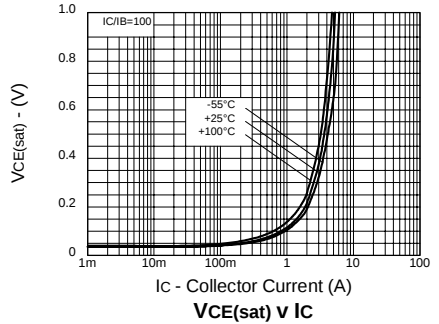
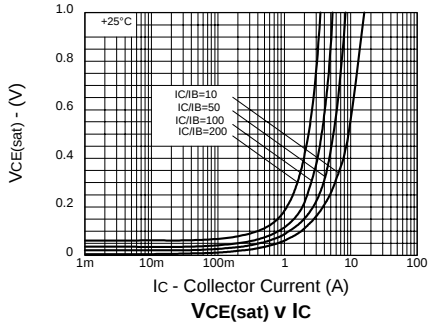
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL				UNIT	CONDITIONS.
		MIN.	TYP.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-30	-70		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CES}$	-25	-60		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-25	-60		V	$I_C = -10\text{mA}^*$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEV}$	-25	-60		V	$I_C = -100\mu\text{A}$, $V_{EB} = +1\text{V}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	-8.5		V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	I_{CBO}		-0.3	-100	nA	$V_{CB} = -24\text{V}$
Emitter Cut-Off Current	I_{EBO}		-0.3	-100	nA	$V_{EB} = -4\text{V}$
Collector Emitter Cut-Off Current	I_{CES}		-0.3	-100	nA	$V_{CE} = -20\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-45	-80	mV	$I_C = -0.1\text{A}$, $I_B = -1.0\text{mA}^*$
			-100	-170	mV	$I_C = -0.5\text{A}$, $I_B = -3\text{mA}^*$
			-140	-240	mV	$I_C = -1\text{A}$, $I_B = -7\text{mA}^*$
			-170	-260	mV	$I_C = -2\text{A}$, $I_B = -30\text{mA}^*$
			-200	-300	mV	$I_C = -3\text{A}$, $I_B = -70\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-870	-1000	mV	$I_C = -3\text{A}$, $I_B = -70\text{mA}^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		-800	-900	mV	$I_C = -3\text{A}$, $V_{CE} = -2\text{V}^*$
Static Forward Current Transfer Ratio	h_{FE}	270 250 195 115	450 400 320 190 50	800		$I_C = -10\text{mA}$, $V_{CE} = -2\text{V}^*$ $I_C = -0.5\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -2\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -5\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -10\text{A}$, $V_{CE} = -2\text{V}^*$
Transition Frequency	f_T		135		MHz	$I_C = -50\text{mA}$, $V_{CE} = -10\text{V}$ $f = 50\text{MHz}$
Output Capacitance	C_{cb}		50		pF	$V_{CB} = -10\text{V}$, $f = 1\text{MHz}$
Switching Times	t_{on}		150		ns	$I_C = -4\text{A}$, $I_B = -40\text{mA}$, $V_{CC} = -10\text{V}$
	t_{off}		270		ns	$I_C = -4\text{A}$, $I_B = \pm 40\text{mA}$, $V_{CC} = -10\text{V}$

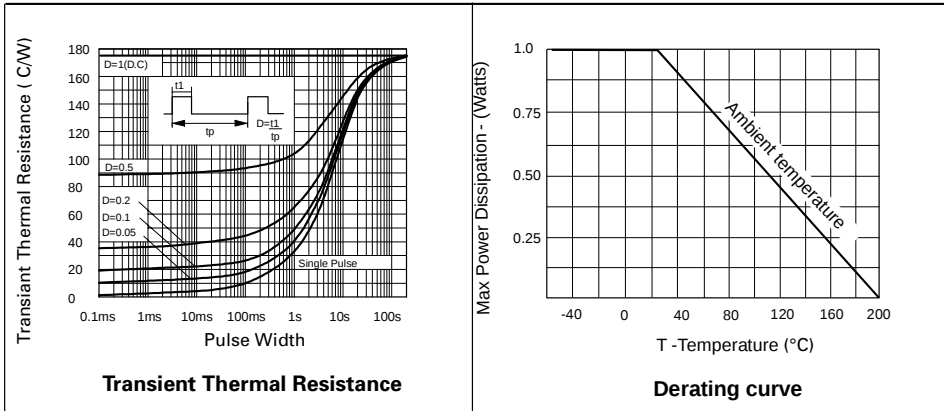
*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$.

ZTX1149A

TYPICAL CHARACTERISTICS



ZTX1149A



*ZETEX ZTX1149 Spice model Last revision 10/1/97

*

.MODEL ZTX1149 PNP IS =9.5e-13 NF=1.002 ISE=1.2e-13 NE =1.4 BF =520
 + VAF=24.97 IKF=5 NR =0.997 ISC=4.5E-13 NC =1.25
 + BR = 40 VAR=2.51 IKR=0.7 RE =20e-3 RB =150e-3
 + RC =10e-3 CJE=490e-12 CJC=150e-12 VJC=1.094
 + MJC= 0.4739 TF =1e-9 TR = 3.5e-9

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*

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